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**Yoshiaki Nakano**

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# Contents

## Part One

xv *Conference Committee*

---

### SILICON PHOTONICS SYMPOSIUM

---

- 6782 02 **Si photonics: past, present, and future (Invited Paper)** [6782-01]  
K. Wada, The Univ. of Tokyo (Japan)
- 6782 03 **Micro/nanoscale silicon based photonic devices (Invited Paper)** [6782-02]  
Z. Zhou, Wuhan National Lab. for Optoelectronics (China) and Georgia Institute of Technology (USA)
- 6782 04 **Ge nanostructures doped silica-on-silicon waveguides (Invited Paper)** [6782-03]  
H. Ou, T. P. Rørdam, K. Rottwitt, F. Grumsen, A. Horsewell, R. W. Berg, P. Shi, L. C. Gontard, R. E. Dunin-Borkowski, Technical Univ. of Denmark (Denmark)

---

### ALL-OPTICAL PROCESSING

---

- 6782 05 **Photonic buffer memory based on polarization bistability in VCSELs (Invited Paper)** [6782-04]  
H. Kawaguchi, Nara Institute of Science and Technology (Japan) and CREST, Japan Science and Technology Agency (Japan)
- 6782 08 **40Gb/s all-optical digital encoder/comparator based on semiconductor optical amplifiers** [6782-07]  
Y. Wang, X. Zhang, J. Dong, D. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 09 **Investigation of ultrafast all-optical AND gate based on cascaded SOAs and optical filters** [6782-08]  
J. Xu, X. Zhang, J. Dong, D. Liu, D. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 0A **Analysis of femtosecond self-polarization modulation in semiconductor optical amplifier** [6782-09]  
M. Liu, A. Yang, Y. Sun, Beijing Institute of Technology (China)

---

**BEST STUDENT PAPER SESSION**

---

- 6782 0B **1.55  $\mu\text{m}$  extremely efficient and polarization insensitive tunable Mach-Zehnder wavelength duplexer based on an InGaAsP/InP ridge waveguide structure (Best Student Paper Award)** [6782-11]  
L. Xu, X. J. M. Leijts, M. J. H. Sander-Jochem, T. de Vries, Y. S. Oei, P. J. van Veldhoven, R. Nötzel, M. K. Smit, Technische Univ. Eindhoven (Netherlands)
- 6782 0C **Ultrafast multifunctional all-optical logic gates based on single semiconductor optical amplifier** [6782-12]  
J. Dong, X. Zhang, Wuhan National Lab. for Optoelectronics (China); S. Fu, Nanyang Technological Univ. (Singapore); Y. Wang, D. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 0D **Electrooptic properties of InGaAsP-based asymmetric double quantum well electroabsorption modulators** [6782-13]  
D. K. Kim, D. S. Citrin, Georgia Institute of Technology (USA) and Georgia Tech-CNRS, Georgia Tech Lorraine (France)
- 6782 0E **The spectral feature analysis of semiconductor thin disk laser** [6782-14]  
C. He, Changchun Institute of Optics, Fine Mechanics and Physics (China) and Graduate School of the Chinese Academy of Science (China); L. Qin, Changchun Institute of Optics, Fine Mechanics and Physics (China); J. Li, L. Cheng, X. Liang, Changchun Institute of Optics, Fine Mechanics and Physics (China) and Graduate School of the Chinese Academy of Science (China); Y. Ning, L. Wang, Changchun Institute of Optics, Fine Mechanics and Physics (China)
- 6782 0F **Variable wavelength conversion based on fan-out grating in QPM-LN** [6782-15]  
Y. Wang, Y. Huang, Z. Weng, H. Yan, R. Ye, J. Zhu, Xiamen Univ. (China)

---

**PHOTONIC INTEGRATION**

---

- 6782 0H **Design and fabrication of a novel monolithically integrated dual-wavelength tunable photodetector** [6782-17]  
J. Lv, H. Huang, Y. Huang, X. Ren, A. Miao, Y. Li, H. Du, Q. Wang, Beijing Univ. of Posts and Telecommunications (China)
- 6782 0I **Multiplication characteristics of InP/InGaAs avalanche photodiodes with thick multiplication and charge layers** [6782-18]  
Y. Zhao, Wuhan National Lab. for Optoelectronics (China)
- 6782 0J **On the performance analysis and design of a novel shared-layer integrated device using RCE-p-i-n-PD/SHBT** [6782-19]  
S. Zhou, Zhejiang Univ. of Technology (China); D. Xiong, Guangdong Univ. of Technology (China); Y. Qin, Zhejiang Univ. of Technology (China); H. Cui, Y. Chong, A. Miao, J. Lv, Beijing Univ. of Posts and Telecommunications (China); J. Gao, Institute of Semiconductors (China)
- 6782 0K **Modulation responses and problems of a novel monolithically integrated optical transceiver for EPON** [6782-20]  
H. Zhang, W. Li, T. Wang, Wuhan National Lab. for Optoelectronics (China)

- 6782 OL **InP-based optoelectronic components for all optical communication (Invited Paper)** [6782-21]  
Y. Baek, D. K. Oh, Electronics and Telecommunications Research Institute (South Korea)

---

#### MICRO LASERS

---

- 6782 OM **InP-based long wavelength VCSELs: their characteristics and applications (Invited Paper)** [6782-22]  
N. Nishiyama, Tokyo Institute of Technology (Japan); C. Caneau, M. Sauer, A. Kobayakov, C. E. Zah, Corning Inc. (USA)
- 6782 ON **Moving from ultrafast VCSELs to MIXSELs: a new class of ultrafast semiconductor lasers (Invited Paper)** [6782-23]  
T. Südmeyer, D. J. H. C. Maas, A.-R. Bellancourt, B. Rudin, M. Golling, H. J. Unold, U. Keller, ETH Zürich (Switzerland)
- 6782 OO **High power VCSEL device with periodic gain active region** [6782-24]  
Y. Q. Ning, L. Qin, Y. F. Sun, T. Li, J. J. Cui, B. Peng, G. Y. Liu, Y. Zhang, Y. Liu, L. J. Wang, Changchun Institute of Optics, Fine Mechanics and Physics (China); D. F. Cui, Z. Y. Xu, Institute of Physics (China)
- 6782 OP **Loss-reduced semiconductor ring lasers based on active vertical coupler structure and two-section rectangular cavity** [6782-25]  
R. Zhang, O. Ansell, Z. Ren, S. Yu, Univ. of Bristol (United Kingdom)

---

#### NOVEL APPLICATION

---

- 6782 OR **Optical gain in 407nm and 470nm InGaN/GaN heterostructures: signature of quantum-dot states** [6782-27]  
B. Witzigmann, S. Steiger, M. Tomamichel, R. Veprek, ETH Zürich (Switzerland); U. T. Schwarz, Univ. of Regensburg (Germany)
- 6782 OS **Analysis of the focusing performance of microlens made of anisotropically dielectric material by multi-wavelength illumination** [6782-28]  
J. Liu, S. Wang, F. Sun, C. Hu, G. Zhang, Beijing Jiaotong Univ. (China)
- 6782 OT **Applications of swept light sources in imaging, sensor, and tests (Invited Paper)** [6782-29]  
T. Li, Y. Tang, W. Xu, Q. Qi, D. Eu, InPhenix, Inc. (USA)

---

#### QUANTUM WELL OPTICAL MODULATORS

---

- 6782 OU **Design and fabrication of high-performance InGaAsP/InP electroabsorption modulator** [6782-37]  
H. Yang, M. K. Chin, Nanyang Technological Univ. (Singapore); D. C. S. Lim, DSO National Labs. (Singapore); J. Zhou, Institute of Semiconductors (China); S. Lee, Nanyang Technological Univ. (Singapore); Y. Cheng, H. Zhu, W. Chen, Institute of Semiconductors (China)

- 6782 0W **Nano-structured special quantum well for high-performance optical modulators (Invited Paper)** [6782-39]  
T. Arakawa, Yokohama National Univ. (Japan); K. Tada, Kanazawa Institute of Technology (Japan)
- 6782 0Y **Design and performance of monolithic integrated electro-absorption modulated distributed feedback laser** [6782-41]  
Y. Cheng, J. Pan, F. Zhou, B. Wang, H. Zhu, L. Zhao, W. Wang, Institute of Semiconductors (China)

---

#### PHOTONIC CRYSTALS AND FIBERS

---

- 6782 0Z **Silicon based ultra-compact modulator with photonic crystal** [6782-30]  
R. Hao, A. Mao, J. Feng, D. Gao, Wuhan National Lab. for Optoelectronics (China); Z. Zhou, Wuhan National Lab. for Optoelectronics (China) and Georgia Institute of Technology (USA); D. S. Citrin, Georgia Institute of Technology (USA)
- 6782 10 **Negative refraction and birefringence in a two-dimensional flat perfect photonic crystal** [6782-31]  
Z. Li, Univ. of Shanghai for Science and Technology (China) and Henan Univ. (China); B. Liang, H. Guo, J. Chen, S. Zhuang, Univ. of Shanghai for Science and Technology (China)
- 6782 11 **Broad-band local field enhancement of a 2D nano-cavity** [6782-32]  
X. Su, F. Liu, J. Liu, S. Jian, Beijing Jiaotong Univ. (China)
- 6782 12 **Wide-band transmission of slow light in one-dimensional photonic crystal coupled resonator optical waveguide** [6782-33]  
C. Li, H. Tian, B. Liu, Y. Ji, Beijing Univ. of Posts and Telecommunications (China)
- 6782 13 **Continuous-wave optical fiber based supercontinuum light source** [6782-34]  
Z. G. Lu, National Research Council (Canada); Y. Song, National Research Council (Canada) and Concordia Univ. (Canada); J. R. Liu, National Research Council (Canada); X. P. Zhang, Concordia Univ. (Canada)
- 6782 14 **Hybrid mode-locking based on nonlinear polarization rotation in a SOA fiber ring laser** [6782-35]  
F. Wang, Wuhan National Lab. for Optoelectronics (China) and Chongqing Institute of Technology (China); X.-L. Zhang, Chongqing Institute of Technology (China); Z.-M. Wu, G.-Q. Xia, Southwest Univ. (China)
- 6782 15 **Liquid crystal photonic bandgap fiber components (Invited Paper)** [6782-36]  
L. Scolari, T. T. Alkeskjold, D. Noordegraaf, Technical Univ. of Denmark (Denmark); G. Tartarini, P. Bassi, Univ. of Bologna (Italy); A. Bjarklev, Technical Univ. of Denmark (Denmark)

---

## TELECOM AND RF PHOTONICS

---

- 6782 17  **$\lambda/4$  phase-shifted distributed feedback lasers with chirped grating: dynamic single-mode and modulation characteristics analyses** [6782-43]  
X.-H. Jia, Sichuan Normal Univ. (China); Z.-M. Wu, G.-Q. Xia, Southwest Univ. (China); D.-Z. Zhong, Wuyi Univ. (China); F. Wang, Chongqing Institute of Technology (China); J.-G. Wu, Southwest Univ. (China); H.-T. Chen, The Chinese People's Armed Police Force Academy (China)
- 6782 18 **Field trial of 160 Gb/s all-optical packet switching (Invited Paper)** [6782-44]  
Y. Liu, Eindhoven Univ. of Technology (Netherlands) and Univ. of Electronic Science and Technology of China (China); J. Herrera, Eindhoven Univ. of Technology (Netherlands) and Univ. Politècnica de Valencia (Spain); O. Raz, E. Tangdiongga, Eindhoven Univ. of Technology (Netherlands); J. Marti, F. Ramos, Univ. Politècnica de València (Spain); G. Maxwell, A. Poustie, Ctr. for Integrated Photonics Ltd. (United Kingdom); H. C. H. Mulvad, Technical Univ. of Denmark (Denmark); M. T. Hill, H. de Waardt, G. D. Khoe, A. M. J. Koonen, H. J. S. Dorren, Eindhoven Univ. of Technology (Netherlands)
- 6782 19 **Theoretical analysis of nonlinear polarization rotation influence on optical sampling in semiconductor optical amplifier** [6782-45]  
M. Liu, A. Yang, Y. Sun, Beijing Institute of Technology (China)
- 6782 1A **Design of all-optical UWB monocycle generation for UWB-over-fibre communications** [6782-46]  
J. Dong, X. Zhang, J. Xu, D. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 1B **A simple approach of high-purity millimeter-wave signal photonic generation** [6782-47]  
T. Wang, M. Chen, H. Chen, S. Xie, Tsinghua Univ. (China)

---

## TUNABLE LASERS

---

- 6782 1C **Widely tunable lasers based on mode-hop-free semiconductor laser array (Invited Paper)** [6782-48]  
T. Kurobe, T. Kimoto, K. Muranushi, T. Mukaiharu, M. Ariga, T. Kagimoto, N. Kagi, N. Matsuo, A. Kasukawa, The Furukawa Electric Co., Ltd. (Japan)
- 6782 1D **Automated chip-on-carrier screening of a SOA integrated full band tunable laser (DSDBR)** [6782-49]  
C. Wang, Bookham Technology (Shenzhen) Co., Ltd. (China); G. Dimitropoulos, A. J. Ward, Bookham Technology plc (United Kingdom); G. Yang, X. Wu, Bookham Technology (Shenzhen) Co., Ltd. (China)
- 6782 1E **A compact tunable transmitter assembly for high performance 10 Gbps optical systems** [6782-50]  
Y. Zhang, F. Liu, S. Yu, N. Zhang, Bookham Technology Co. Ltd. (China); P. Mitchell, S. Mayne, L. Nelson, Bookham Technology (United Kingdom)

- 6782 1F **Static properties of widely tunable external cavity semiconductor laser with sampled fiber grating** [6782-51]  
X. He, Wuhan National Lab. for Optoelectronics (China) and Hong Kong Polytechnic Univ. (Hong Kong China); Y. Yu, D. Huang, Wuhan National Lab. for Optoelectronics (China); D. N. Wang, Hong Kong Polytechnic Univ. (Hong Kong China)
- 6782 1G **Theoretical model and simulation of the extremely short external cavity semiconductor laser** [6782-52]  
G. Xia, Z. Wu, J. Wu, Z. Li, Q. Yang, B. Yang, Southwest Univ. (China)
- 6782 1H **Trend and applications of tunable semiconductor lasers (Invited Paper)** [6782-53]  
S.-L. Lee, Y.-T. Pan, Y.-J. Hung, C.-L. Yao, C.-H. Cheng, S.-T. Ji, National Taiwan Univ. of Science and Technology (Taiwan)

---

#### **COST-EFFECTIVE COMPONENTS**

---

- 6782 1I **Advanced component technologies for colourless access networks (Invited Paper)** [6782-54]  
C. Kazmierski, Alcatel-Thales III-V Lab. (France); P. Chanclou, France Telecom Division R&D (France); J. A. Lazaro, Univ. Politècnica de Catalunya (Spain)
- 6782 1J **Cost-effective telecom/datacom semiconductor lasers (Invited Paper)** [6782-55]  
N. Chen, D. T. R. Chen, W. Hsin, S. B. Chen, F. Xiong, H. Erlig, P. Chen, X. Yeh, D. C. Scott, Archcom Technology, Inc. (USA); A. Sherer, California Institute of Technology (USA)
- 6782 1K **980 nm pump laser module with 750 mW output power** [6782-56]  
B. Guo, J. Lin, Q. He, Bookham Technology Co., Ltd. (China); S. Loten, J. Greatrex, Bookham Technology plc (United Kingdom); H.-U. Pfeiffer, S. Mohrdiek, T. Pliska, Bookham AG (Switzerland)
- 6782 1L **Design of taper coupler for effective laser and single mode fiber coupling with large tolerance** [6782-57]  
J. Zhang, R. V. Pamidighantam, J. H.-S. Lau, Q. Zhang, C. Jayakrishnan, C. W. Tan, M. C. Jong, C. Teo, L. Wei, D. L. Kwong, Institute of Microelectronics (Singapore)
- 6782 1M **Photonics studies on dilute nitrides at long wavelength for telecommunication (Invited Paper)** [6782-58]  
C. S. Peng, M. Pessa, Tampere Univ. of Technology (Finland)

---

#### **MODULATORS AND SWITCHES**

---

- 6782 1N **Intersubband photonic devices by group-III nitrides (Invited Paper)** [6782-59]  
P. Holmström, Royal Institute of Technology (Sweden) and Sophia Univ. (Japan); X. Y. Liu, Chalmers Univ. of Technology (Sweden); H. Uchida, Sophia Univ. (Japan); T. Aggerstam, Royal Institute of Technology (Sweden); A. Kikuchi, K. Kishino, Sophia Univ. (Japan); S. Lourduoss, Royal Institute of Technology (Sweden); T. G. Andersson, Chalmers Univ. of Technology (Sweden); L. Thylén, Royal Institute of Technology (Sweden)



- 6782 1P **Investigation on electro-optic single-sideband modulation using period phase reversal electrode** [6782-61]  
J. Hu, X. Yuan, Wuhan National Lab. for Optoelectronics (China)
- 6782 1Q **Design of a novel high-speed magneto-optic modulator** [6782-62]  
J. Wan, Y. Huang, Z. Weng, H. Yan, Y. Wang, Z. Wu, R. Ye, Xiamen Univ. (China)

## Part Two

---

### NOVEL PHOTONICS COMPONENTS

- 6782 1R **Birefringent hollow core fibers (Invited Paper)** [6782-63]  
P. J. Roberts, Danish Technical Univ. (Denmark)
- 6782 1S **Experimental demonstration of PPLN-based double ring fiber laser and its application to 40 Gb/s wavelength conversion** [6782-64]  
J. Wang, J. Sun, Q. Sun, Wuhan National Lab. for Optoelectronics (China)
- 6782 1T **Light waveguide electro-optical printed circuit board** [6782-65]  
F. Luo, M. Cao, X. Zhou, J. Xu, Z. Luo, J. Yuan, Huazhong Univ. of Science and Technology (China) and Wuhan National Lab. for Optoelectronics (China); L. Zong, C. Zhang, Huazhong Univ. of Science and Technology (China)
- 6782 1U **Carbon-nanotube-based photonic devices (Invited Paper)** [6782-68]  
S. Yamashita, Univ. of Tokyo (Japan)

---

### QUANTUM STRUCTURE DEVICES

- 6782 1V **InAs/InP-based quantum dot mode-locked semiconductor lasers at 1.5  $\mu\text{m}$  (Invited Paper)** [6782-69]  
G.-H. Duan, F. Lelarge, B. Dagens, R. Brenot, A. Accard, A. Shen, F. van Dijk, D. Make, O. Le Gouezigou, L. Le Gouezigou, J.-G. Provost, F. Poingt, J. Landreau, O. Drisse, E. Derouin, B. Rousseau, F. Pommereau, Alcatel Thales III-V Lab. (France)
- 6782 1W **Influence of flux on the growth of InAs quantum dots on GaAs patterned substrate** [6782-70]  
Y. Song, Z. Yu, Y. Liu, Beijing Univ. of Posts and Telecommunications (China) and Key Lab. of Optical Communication and Lightwave Technologies (China)
- 6782 1X **The strain energy distribution of the capping layer surface for InAs/GaAs quantum dot along different growth directions** [6782-71]  
Z. Yu, Y. Liu, Beijing Univ. of Posts and Telecommunications (China)
- 6782 1Y **Quantum-dot semiconductor waveguide devices** [6782-72]  
Z. G. Lu, J. R. Liu, S. Raymond, P. J. Poole, P. J. Barrios, S. Haffouz, D. Poitras, G. Pakulski, National Research Council (Canada); S. Taebi, National Research Council (Canada) and Univ. of Ottawa (Canada); Y. Song, National Research Council (Canada) and Concordia Univ. (Canada); X. P. Zhang, Concordia Univ. (Canada); T. Hall, Univ. of Ottawa (Canada)

- 6782 17 **The couple electronic state of the stack quantum dots by axial symmetrical finite element analysis** [6782-73]  
Y. Liu, Z. Yu, Beijing Univ. of Posts and Telecommunications (China) and Key Lab. of Optical Communication and Lightwave Technologies (China); X. Ren, Key Lab. of Optical Communication and Lightwave Technologies (China)
- 6782 20 **Determination on wave function of quantum structures using finite-difference time domain** [6782-74]  
B. Jia, Z. Yu, Y. Liu, Beijing Univ. of Posts and Telecommunications (China) and Key Lab. of Optical Communication and Lightwave Technologies (China)

---

#### POSTER SESSION

---

- 6782 22 **Resonant-cavity based monolithic white light-emitting diode** [6782-76]  
L. Huang, D. Huang, F. Wen, Wuhan National Lab. for Optoelectronics (China)
- 6782 23 **Multi-quantum-well InGaNs/GaAs resonant cavity enhanced photodetector with integrated vertical taper structure** [6782-77]  
Y. Xu, Y.-Q. Huang, H. Huang, X.-M. Ren, Beijing Univ. of Posts and Telecommunications (China)
- 6782 24 **High power vertical cavity surface-emitting laser with high reliability** [6782-78]  
C. Yan, Changchun Univ. of Science and Technology (China); G. Lu, C. He, L. Qin, Changchun Institute of Optics, Fine Mechanics and Physics (China)
- 6782 25 **Characterization of white OLEDs** [6782-79]  
W. Chen, L. Lu, Univ. of Electronic Science and Technology of China (China)
- 6782 26 **Parameter optimization of nonlinear SOA in an SOA-MZI packet-level self-synchronization scheme** [6782-80]  
L. Cai, M. Zhang, H. Han, W. Yang, P. Ye, Beijing Univ. of Posts and Telecommunications (China)
- 6782 27 **Fine-tuning of the spectral efficiency based on tunneling splitting in multiple quantum well system** [6782-81]  
C. Huang, Hunan Institute of Science and Technology (China); J. Sun, Wuhan National Lab. for Optoelectronics (China); J. Liu, Hunan Institute of Science and Technology (China) and Wuhan National Lab. for Optoelectronics (China); W. Hu, Hunan Institute of Science and Technology (China)
- 6782 28 **Large aperture low threshold current 980nm VCSEs fabricated with pulsed anodic oxidation** [6782-82]  
J. Cui, Changchun Institute of Optics, Fine Mechanics and Physics (China) and Graduate School of Chinese Academy of Sciences (China); Y. Ning, Changchun Institute of Optics, Fine Mechanics and Physics (China); T. Li, G. Liu, Y. Zhang, B. Peng, Y. Sun, Changchun Institute of Optics, Fine Mechanics and Physics (China) and Graduate School of Chinese Academy of Sciences (China); L. Wang, Changchun Institute of Optics, Fine Mechanics and Physics (China)

- 6782 29 **Buffer optimization for high-quality InP-on-GaAs(001) quasi-substrates** [6782-83]  
J. Zhou, X. Ren, D. Xiong, J. Lv, Q. Wang, Y. Huang, H. Huang, S. Cai, Beijing Univ. of Posts and Telecommunications (China)
- 6782 2A **Novel scheme to increase the operation speed of a SOA for all-optical wavelength conversion** [6782-84]  
Z. Wu, Y. Huang, Z. Weng, H. Yan, Y. Wang, J. Wan, R. Ye, Xiamen Univ. (China)
- 6782 2C **Novel optical modulator of silicon photonic crystals** [6782-86]  
J. Li, J. Li, China Jiliang Univ. (China)
- 6782 2D **Structural and optical properties of InGaN/GaN multiple quantum wells structure for ultraviolet emission** [6782-87]  
B. Wang, Hebei Univ. of Science and Technology (China) and Institute of Semiconductors (China); X. Wang, Institute of Semiconductors (China); H. Wen, R. Wu, Hebei Univ. of Science and Technology (China); G. Hu, J. Ran, H. Xiao, Institute of Semiconductors (China)
- 6782 2E **Theory study of AlInGaN quantum well with different barriers** [6782-88]  
F. Wen, Huazhong Univ. of Science and Technology (China) and Univ. of Electronic Science and Technology (China); D. Liu, Huazhong Univ. of Science and Technology (China); L. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 2F **Picosecond pulse Raman amplification and controlled time delay in silicon-on-insulator waveguides** [6782-89]  
J. Wu, F. Luo, M. Cao, Q. Zhang, Y. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 2G **Research of photodetector and its array in standard CMOS technology** [6782-90]  
J. Bian, Jiangsu Polytechnic Univ. (China) and Xiamen Univ. (China); X. Cheng, C. Chen, Xiamen Univ. (China)
- 6782 2H **Single-SOA-based all-optical XNOR and AND gates** [6782-91]  
P. Li, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China); D. Huang, X. Zhang, Wuhan National Lab. for Optoelectronics (China); G. Zhu, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China)
- 6782 2I **Luminescence properties of Cu and Cu,Al doped ZnS quantum dots** [6782-92]  
X. Zhang, Tianjin Univ. of Technology (China) and Nankai Univ. (China); L. Li, Tianjin Univ. of Technology (China); X. Dong, G. Kai, Nankai Univ. (China); D. Dong, Y. Zhang, J. Li, Tianjin Univ. of Technology (China)
- 6782 2J **NIR luminescence properties of ZnS:Er,Yb quantum dots** [6782-93]  
X. Zhang, Nankai Univ. (China) and Tianjin Univ. of Technology (China); X. Dong, Nankai Univ. (China); L. Li, Tianjin Univ. of Technology (China); Z. Wang, Y. Liu, Nankai Univ. (China); D. Dong, Y. Zhang, Tianjin Univ. of Technology (China); G. Kai, Nankai Univ. (China)
- 6782 2K **Two-dimensional photonic crystal polarizer modulated by silicon resin** [6782-94]  
C. Tan, X. Huang, South China Normal Univ. (China)

- 6782 2L **Simulation and analysis of gain-transparent SOA used as optical phase-modulator in DPSK applications** [6782-95]  
W. Hong, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China); D. Huang, X. Zhang, Wuhan National Lab. for Optoelectronics (China); G. Zhu, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China);
- 6782 2M **Finite element method analysis of LiNbO<sub>3</sub> fiber type modulator** [6782-96]  
J. Li, J. Li, China Jiliang Univ. (China)
- 6782 2N **Noise-reduction of experimental optical chaos and its attributes** [6782-99]  
Z. Zhu, Y. Meng, N. Fang, Z. Huang, Shanghai Univ. (China)
- 6782 2P **Modeling of dynamics of DBR tunable lasers based on transfer matrix method** [6782-101]  
S. Kai, Y. Yu, Wuhan National Lab. for Optoelectronics (China)
- 6782 2Q **The spectrum of chaos signal based on Wigner distribution** [6782-102]  
X. Guo, N. Fang, Z. Huang, Shanghai Univ. (China)
- 6782 2R **Activation experiments and quantum efficiency theory on gradient-doping NEA GaAs photocathodes** [6782-103]  
J. Zou, Nanjing Univ. of Science and Technology (China) and East China Institute of Technology (China); Z. Yang, J. Qiao, P. Gao, B. Chang, Nanjing Univ. of Science and Technology (China)
- 6782 2S **Design of high performance DBR lasers for WDM fiber optic communications** [6782-104]  
H. H. Yee, C. L. Xiao, C. K. Liao, H. Y. Tung, H. H. Lu, National Taipei Univ. of Technology (Taiwan)
- 6782 2W **Simulation of integrated DFB lasers in serial in a convenient model with transfer matrices method** [6782-108]  
H. Xie, Y. Wang, W. Zhang, L. He, Y. Sha, W. Zhang, Beijing Univ. of Technology (China)
- 6782 2X **Design of preamplifier for PIN/ HBT OEIC optical receiver** [6782-109]  
Q. Wu, Y.-Q. Huang, H. Huang, H. L. Cui, Y. Q. Li, A. Miao, X.-M. Ren, Beijing Univ. of Posts and Telecommunications (China)
- 6782 2Y **Tunable ultraviolet laser source from a frequency doubled Alexandrite laser** [6782-110]  
S. Liu, Changchun Institute of Optics, Fine Mechanics and Physics (China) and Graduate School of Chinese Academy of Sciences (China); J. Liu, China Northern Institute of Electric Equipment (China); L. Wang, Changchun Institute of Optics, Fine Mechanics and Physics (China)
- 6782 2Z **The role of dispersive magnetic permeability in ultrashort electromagnetic pulse propagation in nonlinear metamaterials** [6782-111]  
S. Wen, Q. Lv, X. Cheng, L. Jiang, W. Su, Hunan Univ. (China)
- 6782 30 **All-optical ultrawideband monocycle and doublet generation using cascaded PPLN waveguides** [6782-112]  
J. Wang, J. Sun, Q. Sun, Wuhan National Lab. for Optoelectronics (China)

- 6782 31 **Analysis and measurement of thermal-electrical performance of microbolometer detector** [6782-113]  
L. Sun, B. Chang, J. Zhang, Y. Qiu, Y. Qian, S. Tian, Nanjing Univ. of Science and Technology (China)
- 6782 32 **Three-input ultrahigh-speed all-optical AND and NOR gates based on orthogonal dual-pump four-wave mixing in semiconductor optical amplifier with PoISK modulated signals** [6782-114]  
P. Li, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China); D. Huang, X. Zhang, Wuhan National Lab. for Optoelectronics (China); G. Zhu, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China)
- 6782 33 **Theoretical investigation and experimental demonstration of nonlinear patterning suppression in bulk semiconductor optical amplifiers for transient cross phase modulation** [6782-115]  
E. Zhou, X. Zhang, D. Huang, Wuhan National Lab. for Optoelectronics (China)
- 6782 34 **Structural and photoluminescence properties of porous silicon with r.f.-sputtered thin films** [6782-116]  
Y. Zhang, Xi'an Jiatong Univ. (China); Z. Jia, Xinjiang Univ. (China)
- 6782 35 **The cavity enhancing effect of F-P cavity mode on the non-degenerated four-wave mixing in distributed-feedback semiconductor laser diodes** [6782-117]  
J. Wu, G. Xia, Southwest Univ. (China); X. Jia, Sichuan Normal Univ. (China); X. Yan, J. Li, X. Wang, Z. Wu, Southwest Univ. (China)
- 6782 37 **Performance analysis of all optical XOR gate using quantum dot semiconductor optical amplifier-based Mach-Zehnder interferometer** [6782-119]  
H. Han, F. Zhang, W. Yang, L. Cai, M. Zhang, P. Ye, Beijing Univ. of Posts and Telecommunications (China)
- 6782 38 **High efficiency 160 Gb/s all-optical wavelength converter based on terahertz optical asymmetric demultiplexer with quantum dot semiconductor optical amplifier** [6782-120]  
H. Han, F. Zhang, W. Yang, L. Cai, M. Zhang, P. Ye, Beijing Univ. of Posts and Telecommunications (China)
- 6782 39 **Linear frequency modulation with electronic-optics modulator** [6782-121]  
C. Cao, X. Zeng, Y. Zheng, H. Liu, X. Zhao, Xidian Univ. (China)
- 6782 3A **Study on the collimation of laser diode beams** [6782-122]  
Y. Zheng, X. Zeng, C. Cao, Z. Feng, Xidian Univ. (China)
- 6782 3B **Focused light from a metallic nanostructure composed by a nanoparticle and a nanoslit** [6782-123]  
G. Zhang, J. Liu, C. Hu, F. Sun, X. Su, Beijing Jiaotong Univ. (China)

- 6782 3C **Numerical investigation of differential phase noise and its power penalty for optical amplification using semiconductor optical amplifiers in DPSK applications** [6782-124]  
W. Hong, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China); D. Huang, X. Zhang, Wuhan National Lab. for Optoelectronics (China); G. Zhu, Wuhan National Lab. for Optoelectronics (China) and Huazhong Univ. of Science and Technology (China)
- 6782 3D **On-line measurement system of GaAs photocathodes and its applications** [6782-125]  
J. Zou, Nanjing Univ. of Science and Technology (China) and East China Institute of Technology (China); L. Feng, G. Lin, Y. Rao, East China Institute of Technology (China); Z. Yang, Y. Qian, B. Chang, Nanjing Univ. of Science and Technology (China)

*Author Index*

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